Ideal for space critical applications, the LM4431

voltage reference is available in the sub-miniature

(3 mm x 1.3 mm) SOT-23 surface-mount package.

The LM4431's advanced design eliminates the need for an external stabilizing capacitor while ensuring

stability with any capacitive load, thus making the LM4431 easy to use. The operating current range is

The LM4431 utilizes fuse and zener-zap reverse

breakdown voltage trim during wafer sort to ensure

that the parts have an accuracy of better than ±2.0% at 25°C. Bandgap reference temperature drift

curvature correction and low dynamic impedance

ensure stable reverse breakdown voltage accuracy

over a wide range of operating temperatures and



LM4431 Micropower Shunt Voltage Reference

Check for Samples: LM4431

DESCRIPTION

 $100 \mu A$ to 15 mA.

currents.

FEATURES

- **Small Package: SOT-23**
- **No Output Capacitor Required**
- **Tolerates Capacitive Loads**
- Fixed Reverse Breakdown Voltage of 2.50V

APPLICATIONS

- Portable, Battery-Powered Equipment
- **Data Acquisition Systems**
- Instrumentation
- **Process Control**
- **Energy Management**
- **Product Testing**
- **Power Supplies**

KEY SPECIFICATIONS

- Output Voltage Tolerance: 25°C: ±2.0% (Max)
- Low Output Noise (10 Hz to 10 kHz): 35 μV_{rms}
- Wide Operating Current Range: 100 µA to 15
- Commercial Temperature Range: 0 to +70 °C
- Low Temperature Coefficient: 30 ppm/°C (Typ)

Connection Diagram

Top View



^{*} This pin must be left floating or connected to pin 2.

Figure 1. SOT-23 Package See Package Number DBZ0003A



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Absolute Maximum Ratings (1)(2)

Reverse Current	Reverse Current					
Forward Current	Forward Current					
Power Dissipation $(T_A = 25^{\circ}C)^{(3)}$	306 mW					
Storage Temperature	-65°C to +150°C					
Lood Townsonstons	DD70000A Doctions	Vapor phase (60 seconds)	+215°C			
Lead Temperature	DBZ0003A Package	Infrared (15 seconds)	+220°C			
ECD Consensibility		Human Body Model (4)	2 kV			
ESD Susceptibility		Machine Model (4)	200V			

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The specified specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (3) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is PD_{max} = (T_{Jmax} ¬ T_A)/θ_{JA} or the number given in the Absolute Maximum Ratings, whichever is lower. For the LM4431, T_{Jmax} = 125°C, and the typical thermal resistance (θ_{JA}), when board mounted, is 326°C/W for the SOT-23 package.
- (4) The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.

Operating Ratings⁽¹⁾⁽²⁾

Temperature Range $(T_{min} \le T_A \le T_{max})$		0°C ≤ T _A ≤ +70°C
Reverse Current	LM4431-2.5	100 μA to 15 mA

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The specified specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is PD_{max} = (T_{Jmax} ¬ T_A)/θ_{JA} or the number given in the Absolute Maximum Ratings, whichever is lower. For the LM4431, T_{Jmax} = 125°C, and the typical thermal resistance (θ_{JA}), when board mounted, is 326°C/W for the SOT-23 package.

Product Folder Links: LM4431



LM4431-2.5 Electrical Characteristics

Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} ; all other limits $T_A = T_J = 25$ °C.

Symbol	Parameter	Conditions	Typical ⁽¹⁾	LM4431M3 Limits ⁽²⁾	Units (Limit)
V _R	Reverse Breakdown Voltage	I _R = 100 μA	2.500		V
	Reverse Breakdown VoltageTolerance	I _R = 100 μA		±50	mV (max)
I _{RMIN}	Minimum On anatin a Commant		45		μA
	Minimum Operating Current			100	μA (max)
$\Delta V_R/\Delta T$		I _R = 10 mA	±30		ppm/°C
	Average Reverse Breakdown Voltage Temperature Coefficient	I _R = 1 mA	±30		ppm/°C
	remperature document	I _R = 100 μA	±30		ppm/°C
$\Delta V_R/\Delta I_R$		$I_{RMIN} \le I_R \le 1 \text{ mA}$	0.4		mV
				1.0	mV (max)
	Reverse Breakdown Voltage Change with Operating Current Change			1.2	mV (max)
		1 mA ≤ I _R ≤ 15 mA	2.5		mV
				8.0	mV (max)
				25	mV (max)
Z _R	Reverse Dynamic Impedance	I _R = 1 mA, f = 120 Hz, I _{AC} = 0.1 I _R	1.0		Ω
e _N	Wideband Noise	$I_R = 100 \mu A$, 10 Hz \le f \le 10 kHz	35		μV_{rms}
ΔV_R		t = 1000 hrs			
	Reverse Breakdown Voltage Long Term Stability	T = 25°C ±0.1°C	120		ppm
	Clabinty	I _R = 100 μA			

Product Folder Links: LM4431

 ⁽¹⁾ Typicals are at T_J = 25°C and represent most likely parametric norm.
 (2) Limits are 100% production tested at 25°C. Limits over temperature are ensured through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate AOQL.



Typical Performance Characteristics

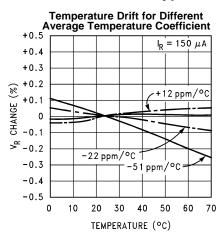
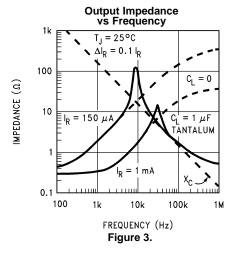
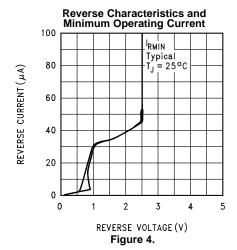
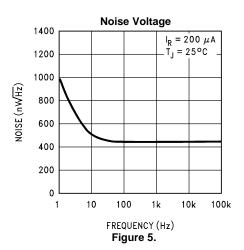


Figure 2.







Start-Up Characteristics

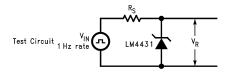


Figure 6. Test Circuit

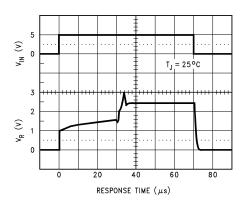
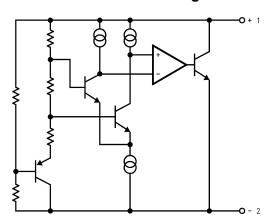


Figure 7. LM4431-2.5, $R_S = 30k$



Functional Block Diagram



APPLICATIONS INFORMATION

The LM4431 is a micro-power curvature-corrected 2.5V bandgap shunt voltage reference. For space critical applications, the LM4431 is available in the sub-miniature SOT-23 surface-mount package. The LM4431 has been designed for stable operation without the need of an external capacitor connected between the "+" pin and the "-" pin. If, however, a bypass capacitor is used, the LM4431 remains stable. The operating current range is $100 \, \mu A$ to $15 \, m A$.

The LM4431's SOT-23 package has a parasitic Schottky diode between pin 2 (–) and pin 3 (Die attach interface contact). Therefore, pin 3 of the SOT-23 package must be left floating or connected to pin 2.

In a conventional shunt regulator application (Figure 8), an external series resistor (R_S) is connected between the supply voltage and the LM4431. R_S determines the current that flows through the load (I_L) and the LM4431 (I_Q). Since load current and supply voltage may vary, R_S should be small enough to supply at least the minimum acceptable I_Q to the LM4431 even when the supply voltage is at its minimum and the load current is at its maximum value. When the supply voltage is at its maximum and I_L is at its minimum, R_S should be large enough so that the current flowing through the LM4431 is less than 15 mA.

 R_S is determined by the supply voltage, (V_S) , the load and operating current, $(I_L$ and $I_Q)$, and the LM4431's reverse breakdown voltage, V_R .

$$R_{S} = \frac{V_{S} - V_{R}}{I_{L} + I_{Q}} \tag{1}$$

Typical Applications

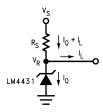


Figure 8. Shunt Regulator

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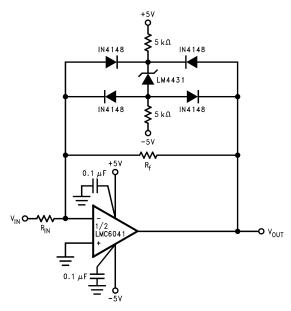


Figure 9. Bounded amplifier reduces saturation-induced delays and can prevent succeeding stage damage.

Nominal clamping voltage is ±3.9V (LM4431's reverse breakdown voltage +2 diode V_F).

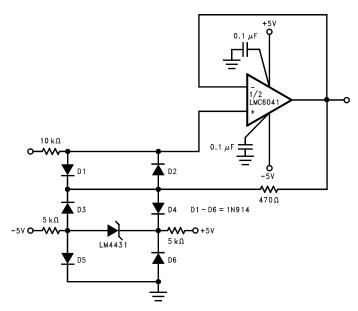
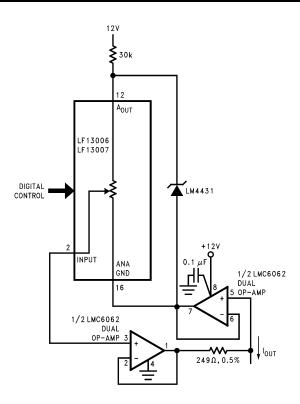


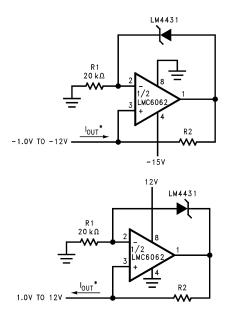
Figure 10. Protecting Op Amp input. The bounding voltage is $\pm 4V$ with the LM4431 (LM4431's reverse breakdown voltage + 3 diode V_F).





$$I_{OUT} = \frac{2.5V}{249\Omega} \left[\frac{1}{\text{gain set #}} \right]$$

Figure 11. Programmable Current Source



 $*I_{OUT} = \frac{2.5V}{R2}$

Figure 12. Precision 1 µA to 1 mA Current Sources



REVISION HISTORY

Changes from Revision B (April 2013) to Revision C			
•	Changed layout of National Data Sheet to TI format	7	



PACKAGE OPTION ADDENDUM

11-Jan-2021

PACKAGING INFORMATION

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
LM4431M3-2.5	NRND	SOT-23	DBZ	3	1000	Non-RoHS & Green	Call TI	Call TI	0 to 70	S2E	
LM4431M3-2.5/NOPB	ACTIVE	SOT-23	DBZ	3	1000	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	S2E	Samples
LM4431M3X-2.5/NOPB	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	S2E	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

11-Jan-2021

n no event shall TI's liabili	tv arising out of such information	exceed the total purchase	price of the TI part(s) at issue in this document sold by	y TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM4431M3-2.5	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM4431M3-2.5/NOPB	SOT-23	DBZ	3	1000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
LM4431M3X-2.5/NOPB	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3

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*All dimensions are nominal

7 til dillionolorio aro nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM4431M3-2.5	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM4431M3-2.5/NOPB	SOT-23	DBZ	3	1000	210.0	185.0	35.0
LM4431M3X-2.5/NOPB	SOT-23	DBZ	3	3000	210.0	185.0	35.0



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203227/C





SMALL OUTLINE TRANSISTOR



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration TO-236, except minimum foot length.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



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